



2. Konferenca Mladih Odseka F8

# Homogenost sevalnega polja v okolici gorivnih elementov

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Motivacija

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Testni primeri fluksa žarkov gama Simetrija Število elementov Velikost kanala

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Homogenost polja
— Motivacija

· Slikanje z magnetno resonanco (MRI)



Homogenost polja - Motivacija

- · Slikanje z magnetno resonanco (MRI)
- TEA laserji



Slika: Maggs, P., 2008, CO2 TEA Laser Electrical Circuit, http://commons.wikimedia.org/wiki/File:TEA-Laser-Circuit.jpg



Homogenost polja - Motivacija

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- Dopiranje kristalov v raziskovalnih reaktorjih (Neutron Transmutation Doping of Silicon at Research Reactors, 2012)



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- · Slikanje z magnetno resonanco (MRI)
- TEA laserji
- Dopiranje kristalov v raziskovalnih reaktorjih (*Neutron Transmutation Doping of Silicon at Research Reactors*, 2012)
- · Enakomerno obsevanje vzorcev v polju gama za testiranje vzdržljivosti



# Analitične definicije

· Naključno polje: 
$$\xi(g) = \sum_{\lambda} \sum_{i,j=1}^{d_{\lambda}} z_{ji}^{(\lambda)} T_{ij}^{(\lambda)}(g)$$
, kjer so  
 $z_{ji}^{(\lambda)} = d_{\lambda} \int_{G} \xi(g) \overline{T_{ij}^{(\lambda)}(g)} \, \mathrm{d}g$ , je homogeno (Yaglom, 1961), če:

$$E z_{ji}^{(\lambda)} z_{ik}^{(\mu)} = \delta_{\lambda\mu} \delta_{ik} f_{jl}^{(\lambda)}$$

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· Razvoj $\phi({\bf r})$ v Taylorjevo vrsto okrog ${\bf r}=0$ , primerjava velikosti prvih nekaj členov



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- · Razvoj $\phi({\bf r})$ v Taylorjevo vrsto okrog ${\bf r}=0$ , primerjava velikosti prvih nekaj členov
- · Delovna definicija: Čim bolj konstantno polje



1. Dvotočkovna mera: 
$$\frac{\phi_{\max}}{\phi_{\min}} \in [1,\infty)$$



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- 2. Statistične mere
- 3. Razdalja med matriko  $\phi({\bf r}_i)=\phi(x_i,y_j,z_k)=\left[\Phi\right]_{ijk}$  in konstantno matriko  $\left[E\right]_{ijk}\equiv 1, \forall i,j,k$



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 $\|\mathbf{A}\|_{\mathbf{F}} = \sqrt{\mathbf{U}} \mathbf{V}$ 

4. Porazdelitev največjih razlik:



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- 4. Porazdelitev največjih razlik:
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 $\cdot~$  Histogram porazdelitve  $(v_2-v_1)/\left< v_1 \right>$ 



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- $\cdot~$  Histogram porazdelitve  $\left(v_{2}-v_{1}\right)/\left\langle v_{1}\right\rangle$
- · Percentili:  $P_{75}$ ,  $P_{95}$ ,  $P_{97.5}$





0 Relativne razlike max-min Reaktor9k4 center Pod9o6ica 19. 2. 2015

Lestni primeri fluksa žarkov gama

L\_ Simetrija

# Nesimetrična razporeditev





Lestni primeri fluksa žarkov gama

L\_ Simetrija

# Nesimetrična razporeditev





Testni primeri fluksa žarkov gama

└─ Simetrija

# Nesimetrična razporeditev



Testni primeri fluksa žarkov gama

L\_ Simetrija

# Nesimetrična razporeditev



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– Testni primeri fluksa žarkov gama

└─ Simetrija

### Nesimetrična razporeditev - fluks žarkov gama





Testni primeri fluksa žarkov gama

└─ Simetrija

### Nesimetrična razporeditev - nehomogenost



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Število elementov

# Število gorivnih elementov



Testni primeri fluksa žarkov gama

└─ Število elementov

# Število gorivnih elementov





- Testni primeri fluksa žarkov gama

Število elementov

# Število gorivnih elementov – nehomogenost



- Testni primeri fluksa žarkov gama

Število elementov

# Število gorivnih elementov – nehomogenost



Lestni primeri fluksa žarkov gama

Velikost kanala

### Velikost obsevalnega kanala







Slika: r = 10 cm

Slika:  $r = 2.5 \,\mathrm{cm}$ 



Slika: r = 20 cm



– Testni primeri fluksa žarkov gama

└─ Velikost kanala

### Velikost obsevalnega kanala – nehomogenost



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– Testni primeri fluksa žarkov gama

└─ Velikost kanala

### Velikost obsevalnega kanala – nehomogenost



- Testni primeri fluksa žarkov gama

└─ Velikost kanala

### Velikost obsevalnega kanala – gradient



Slika: r = 2.5 cm

Slika: r = 5 cm

Slika: r = 10 cm



Homogenost polja L Izbor mer

### Najboljše mere homogenosti

Analiza glavnih komponent (angl. principal component analysis, PCA): prva komponenta pojasni 76 % variance



# Najboljše mere homogenosti

# Analiza glavnih komponent (angl. principal component analysis, PCA): prva komponenta pojasni 76 % variance

Mera	Nasičenost
max/median	0.38
max/min	0.38
varianca	0.35
median(grad)	0.18
var(grad)	0.24
Frobenius	0.38
$P_{75}$	0.31
$P_{95}$	0.36
$P_{97.5}$	0.37



Homogenost polja Lizhor mer

# Najboljše mere homogenosti

# Analiza glavnih komponent (angl. principal component analysis, PCA): prva komponenta pojasni 76 % variance

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P <sub>97.5</sub>	0.37

Multipla regresija za napoved vsote mer homogenosti



Homogenost polja L Zaključek

Zaključek

· Več možnosti za ovrednotenje homogenosti polja



Homogenost polja Zaključek

Zaključek

- · Več možnosti za ovrednotenje homogenosti polja
- · Gradient občutljiv na statistične napake



Homogenost polja - Zaključek

Zaključek

- · Več možnosti za ovrednotenje homogenosti polja
- · Gradient občutljiv na statistične napake
- · Vsota več mer



Homogenost polja - Zaključek

# Zaključek

- · Več možnosti za ovrednotenje homogenosti polja
- · Gradient občutljiv na statistične napake
- Vsota več mer
- · Linearnost mere?



Homogenost polja Zaključek

# Hvala za pozornost!



Homogenost polja
Zaključek

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